

## **DESCRIPTION**

These Schottky barrier diodes are designed for high speed applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface package is excellent for hand held and portable applications space is limited.

The BAT54CW is available in SC-70 package

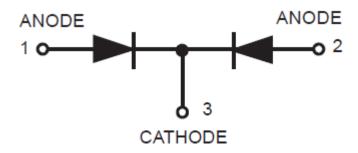
# **FEATURES**

- Extremely Fast Switching Speed
- Low Forward Voltage 0.35 Volts (Typ)
  @ I<sub>F</sub> = 10mAdc
- Available in SC-70 package

#### ORDERING INFORMATION

Package Type	Part Number			
SC-70	BAT54CW			
Note	SPQ: 3,000pcs/Reel			
AiT provides all RoHS Compliant Products				

## PIN DESCRIPTION



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# **ABSOLUTE MAXIMUM RATINGS**

#### $T_A$ =25°C, unless otherwise noted

V <sub>R</sub> , Reverse Voltage	30V
P <sub>D</sub> , Total Device Dissipation FR-5 Board,	
@T <sub>A</sub> = 25°C	225mW
Derate above 25°C	1.8mW/°C
I <sub>F</sub> , DC Forward Current	200mA
T <sub>J</sub> , Junction Temperature	125 °C
T <sub>STG</sub> , Storage Temperature Range	−55°C ~ +150°C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

# **ELECTRICAL CHARACTERISTICS**

T<sub>A</sub> = 25°C, unless otherwise noted

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
Reverse Breakdown Voltage	$V_{(BR)R}$	I <sub>R</sub> =10µA	30	-	-	V
Forward Voltage	VF	I <sub>F</sub> =0.1mA	ı	0.22	0.24	<b>&gt;</b>
		I <sub>F</sub> =1mA	i	0.29	0.32	
		I <sub>F</sub> =10mA	ı	0.35	0.4	
		I <sub>F</sub> =30mA	-	0.41	0.5	
		I <sub>F</sub> =100mA	i	0.52	1	
Reverse Current	I <sub>R</sub>	V <sub>R</sub> =25V	ı	0.5	2	μΑ
Repetitive Peak Forward Current	I <sub>FRM</sub>		-	-	300	mA
Non–Repetitive Peak Forward			-	-	600	mA
Current (t<1.0s)	IFSM					
Total Capacitance	Ст	V <sub>R</sub> =1.0V, f=1.0MHz	-	_	10	рF
Reverse Recovery Time	t <sub>rr</sub>	$I_F=I_R=10$ mA, $I_{R(REC)}=1.0$ mA	-	_	5	ns

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# TYPICAL CHARACTERISTICS

 $T_A = 25^{\circ}C$ 

Figure 1. Forward Characteristics

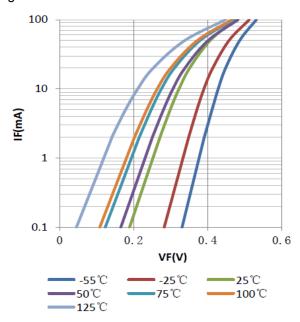


Figure 2. Reverse Characteristics

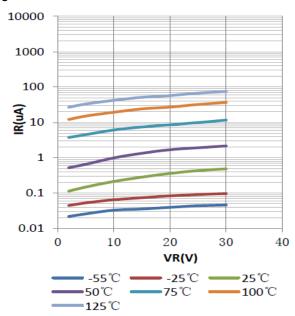
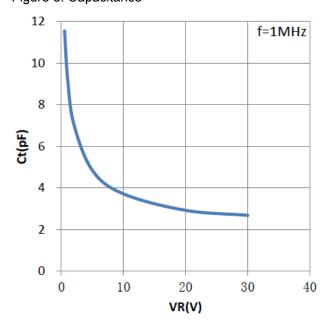


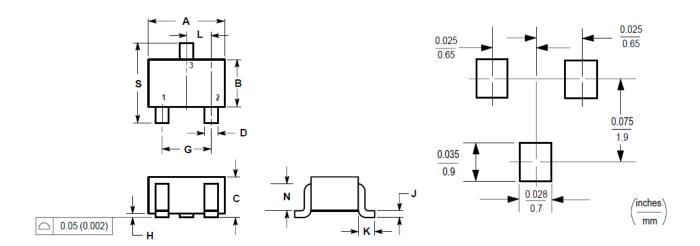
Figure 3. Capacitance



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# PACKAGE INFORMATION

Dimension in SC-70 Package (Unit: mm)



DIM	MILLIN	METERS	INCHES		
	MIN	MAX	MIN	MAX	
Α	1.80	2.20	0.071	0.087	
В	1.15	1.35	0.045	0.053	
С	0.80	1.00	0.032	0.040	
D	0.30	0.40	0.012	0.016	
G	1.20	1.40	0.047	0.055	
Н	0.00	0.10	0.000	0.004	
J	0.10	0.25	0.004	0.010	
K	0.425 REF		0.017 REF		
L	0.650 BSC		0.026 BSC		
N	0.700 REF		0.700 REF 0.028 REF		
S	2.00	2.40	0.079	0.095	

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